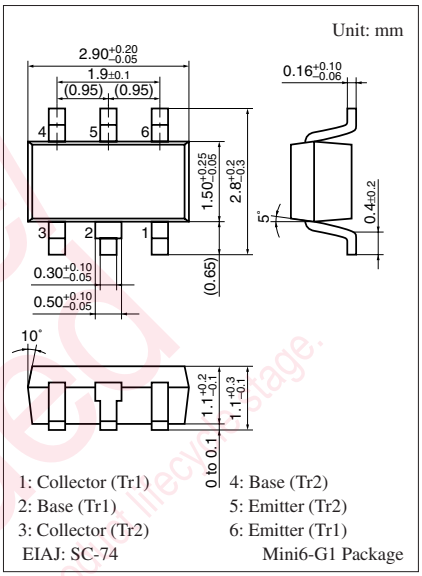
XN06534 (XN6534)

Silicon NPN epitaxial planar type

For high-frequency amplification



Marking Symbol: 7F

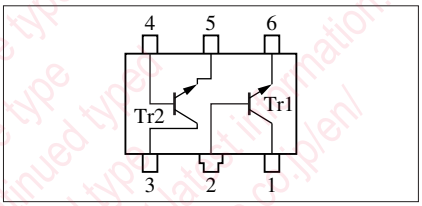
■ Features

- Two elements incorporated into one package
- Reduction of the mounting area and assembly cost by one half

■ Basic Part Number

- 2SC2404 × 2

Internal Connection



■ Absolute Maximum Ratings $T_a = 25°C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	30	V
Collector-emitter voltage (Base open)	V_{CEO}	20	V
Emitter-base voltage (Collector open)	V_{EBO}	3	V
Collector current	I_C	15	mA
Total power dissipation	P_T	200	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	−55 to +150	°C

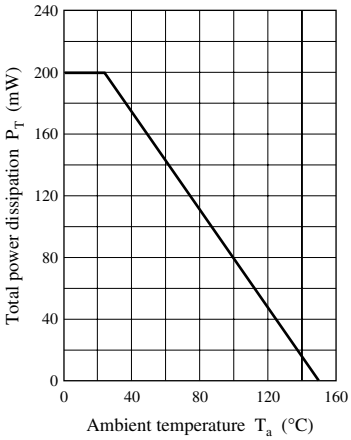
■ Electrical Characteristics $T_a = 25°C \pm 3°C$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	I_C = 10 µA, I_E = 0	30			V
Emitter-base voltage (Collector open)	V_{EBO}	I_E = 10 µA, I_C = 0	3			V
Base-emitter voltage	V_{BE}	V_{CB} = 6 V, I_E = −1 mA		720		mV
Forward current transfer ratio	h_{FE}	V_{CB} = 6 V, I_E = −1 mA	40		260	—
h_{FE} ratio *	$h_{FE(Small/Large)}$	V_{CB} = 6 V, I_E = −1 mA	0.50	0.99		—
Transition frequency	f_T	V_{CB} = 6 V, I_E = −1 mA, f = 200 MHz	450	650		MHz
Reverse transfer capacitance (Common emitter)	C_{re}	V_{CB} = 6 V, I_E = −1 mA, f = 10.7 MHz		0.8	1.0	pF
Power gain	G_P	V_{CB} = 6 V, I_E = −1 mA, f = 100 MHz		24		dB
Noise figure	NF	V_{CB} = 6 V, I_E = −1 mA, f = 100 MHz		3.3		dB

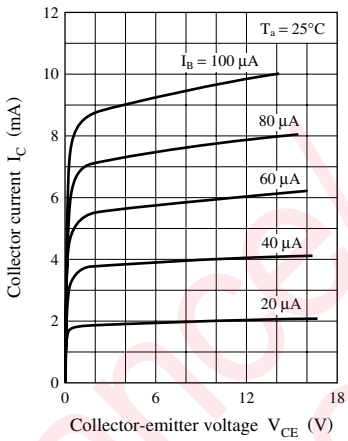
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.
2. *: Ratio between 2 elements

Note) The part number in the parenthesis shows conventional part number.

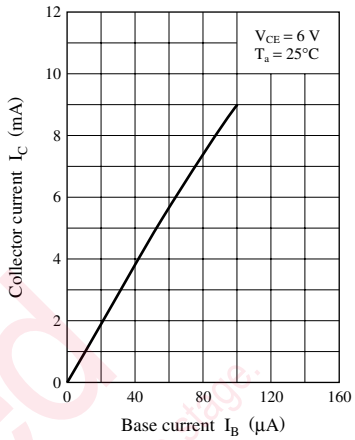
P_T — T_a



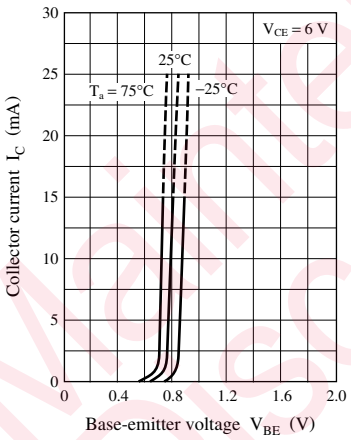
I_C — V_{CE}



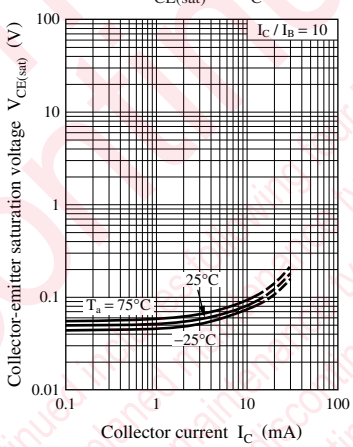
I_C — I_B



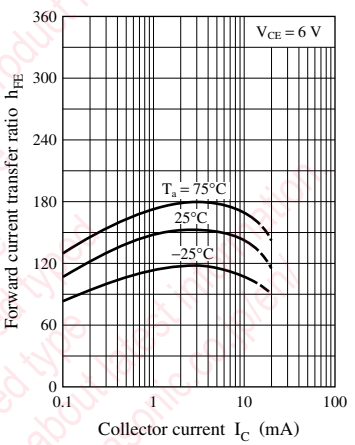
I_C — V_{BE}



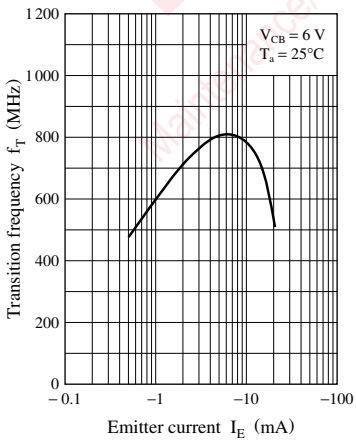
$V_{CE(sat)}$ — I_C



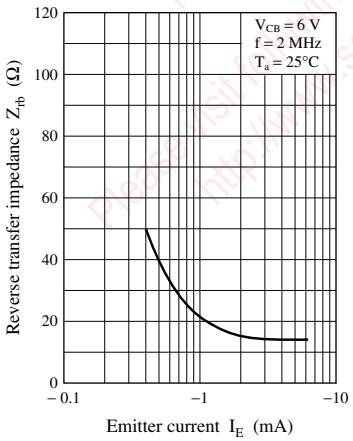
h_{FE} — I_C



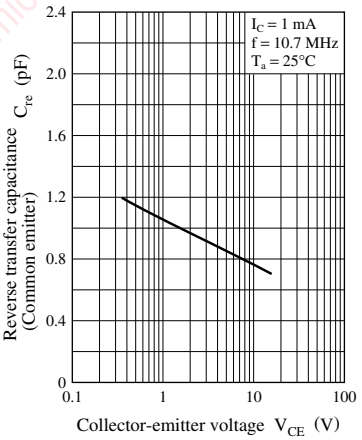
f_T — I_E



Z_{rb} — I_E



C_{re} — V_{CE}



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